

Rev. V7

Features

Very Low Power Consumption: 50 μW

Low Insertion Loss: 1.0 dB

High Isolation: 35 dB up to 2 GHz

Very High Intercept Point: 46 dBm IP3

Nanosecond Switching Speed

Temperature Range: -40°C to +85°C

Low Cost SOIC-8 Plastic Package

Tape and Reel Packaging Available

Description

M/A-COM's SW-259 is a GaAs MMIC SPST switch in a low cost SOIC-8 lead surface mount plastic package. The SW-259 is ideally suited for use where low power consumption is required. Typical applications include transmit/receive switching, switch matrices and switched filter banks in systems such as radio and cellular equipment, PCM, GPS, fiber optic modules, and other battery powered radio equipment.

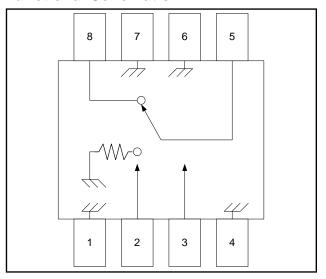
The SW-259 is fabricated using a monolithic GaAs MMIC using a mature 1 micron process. The process features full chip passivation for increased performance and reliability.

Ordering Information ¹

Part Number	Package
SW-259 PIN	Bulk Packaging
SW-259TR	1000 piece reel

^{1.} Reference Application Note M513 for reel size information.

Functional Schematic



Pin Configuration

PIN No.	Description	PIN No.	Description
1	Ground	5	RF2
2	А	6	Ground
3	В	7	Ground
4	Ground	8	RF1

Absolute Maximum Ratings 2

Parameter	Absolute Maximum
Input Power ³ 0.05 GHz 0.5-2.0 GHz	+27 dBm +34 dBm
Control Voltage	+5 V, -8.5 V
Storage Temperature	-65°C to +150°C

- 2. Exceeding any one or combination of these limits may cause permanent damage to this device.
- 3. When the RF Input power is applied to a terminated port, the absolute maximum is +32 dBm.



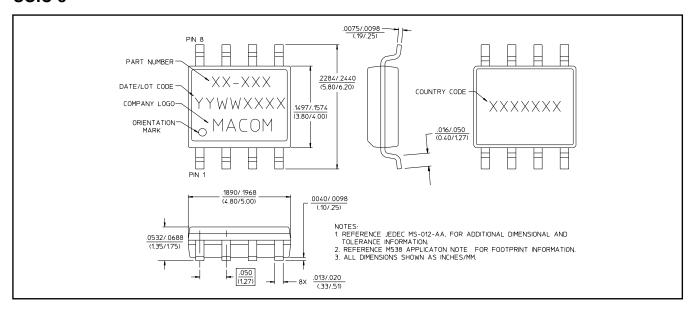
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Electrical Specifications: $T_A = +25$ °C ⁴

Parameter	Test Conditions	Units	Min	Тур	Max
Insertion Loss	DC - 0.1 GHz DC - 0.5 GHz DC - 1.0 GHz DC - 2.0 GHz	dB dB dB dB	_ _ _ _	0.5 0.8 1.0 1.4	0.6 1.0 1.2 1.6
Isolation	DC - 0.1 GHz DC - 0.5 GHz DC - 1.0 GHz DC - 2.0 GHz	dB dB dB dB	62 55 45 32	65 58 48 35	_ _ _ _
VSWR On VSWR Off	DC - 2.0 GHz DC - 2.0 GHz	Ratio Ratio	1.2:1 1.2:1	_	_
1 dB Compression	Input Power 0.05 GHz 0.5-2.0 GHz	dBm dBm		18 23	
Trise, Tfall	10% to 90% RF, 90% to 10% RF	nS	_	4	
Ton, Toff	50% Control to 90% RF, 50% Control to 10% RF	nS	_	8	
Transients	In-Band	mV	_	35	
2nd Order Intercept	Measured Relative to Input Power, two-tone up to +5 dBm 0.05 GHz 0.5 - 2.0 GHz	dBm dBm		55 68	
3rd Order Intercept	Measured Relative to Input Power, two-tone up to +5 dBm 0.05 GHz 0.5 - 2.0 GHz	dBm dBm	_	40 46	_

^{4.} All measurements with 0, -5 V control voltages at 1 GHz in a 50Ω system, unless otherwise specified.

SOIC-8

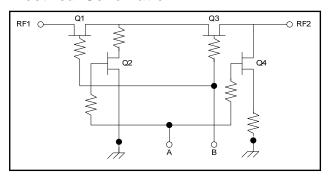


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Electrical Schematic



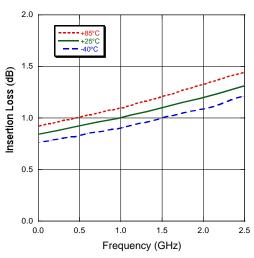
Truth Table 5,6

Control Inputs		Condition of Switch		
Α	В	RF State		
1	0	On		
0	1	Off		

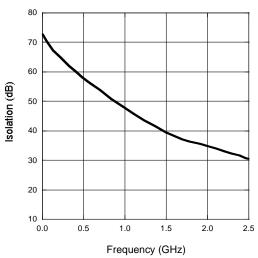
- 5. "0" = 0 to -0.2 V @ 20 mA max.
- 6. "1" = -5 V @ 20 mA Typ to -8V @ 600 mA max.

Typical Performance Curves

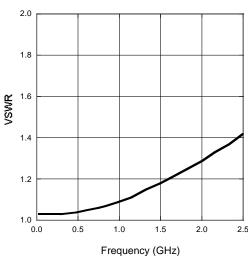
Insertion Loss



Isolation



VSWR



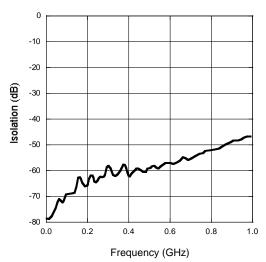
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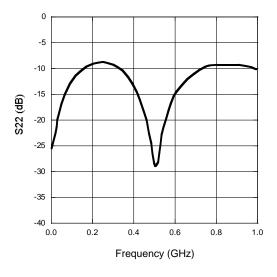
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Swept Data Characterized in 75 Ohms

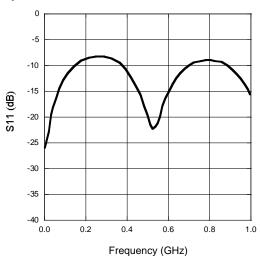
Isolation



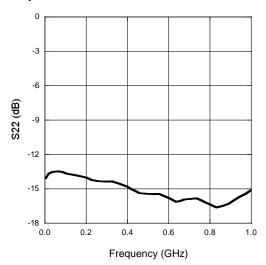
Output Return Loss - On



Input Return Loss - On



Output Return Loss - Off



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